JAN 2-0 1998 3 IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Leonard Forbes et al.

Title: SILICON CARBIDE GATE TRANSISTOR AND FABRICATION PROCESS

Docket No.: 303.326US1 Filed: July 29, 1997

Examiner:

Serial No.: 08/903,486

Due Date: N/A

Group Art Unit: 1104

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Assistant Commissioner for Patents Washington, D.C. 20231

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- X Copy of Filing Receipt (1 pg.)
- $\underline{X}$  A return postcard.
- X Other: Copy of the returned postcard (1 pg).

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<u>CERTIFICATE UNDER 37 CFR 1.8</u>: The undersigned hereby certifies that this Transmittal Letter and the paper, as described above, are being deposited in the United States Postal Service, as first class mail, in an envelope addressed to: Assistant Commissioner for Patents, Washington, D.C. 20231, on this <u>15th</u> day of <u>January</u>, 1998.

SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A. P.O. Box 2938, Minneapolis, MN 55402 (612-373-6900)

Name: Russell D. Slife Reg. No. 39,838

RDS:CMG:dmw



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## **COMMUNICATION RE: INCORRECT FILING RECEIPT**

2011 - 1998

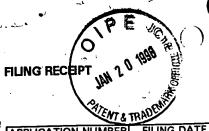
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Applicants hereby request correction of the Filing Receipt with respect to the above-identified patent application. In the Filing Receipt received December 16, 1997, (copy enclosed), the filing date is incorrect and should read: 07/29/97.

Applicants would appreciate the above-identified printing error be corrected and that a new "corrected" filing receipt be sent to Applicants' representatives at the address given below.

I hereby certify that this correspondence is being deposited with the United States Postal Service as first	Respectfully submitted,					
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(Date of Deposit)	By their Representatives,					
Eussell Stifes	SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A. P.O. Box 2938					
	Minneapolis, MN 55402 (612) 373-6965					
Date	By usself D. Stifer					
	Russell D. Slifer Reg. No. 39,838					
	RDS:CMG:dmw					







UNITED STATES DEPARTMENT OF COMMERCE Patent and Trad mark Office ASSISTANT SECRETARY AND COMMISSIONER OF PATENTS AND TRADEMARKS Washington, D.C. 20231

1	APPLICATION NUMBER	FILING DATE	GRP ART UNIT	FIL FEE REC'D	ATTORNEY DOCKET NO.	DRWGS	TOT CL	IND CL
,	08/903,486	07/30/97	1104	\$894.00	303.326US1	4.	. 22 ,	4

SCHWEGMAN LUNDBERG WOESSNER & KLUTH P O BOX 2938 MINNEAPOLIS MN 55402 D/ June 29, 1998-105 D/ July 29, 1998-conv.

Receipt is acknowledged of this nonprovisional Patent Application. It will be considered in its order and you will be notified as to the results of the examination. Be sure to provide the U.S. APPLICATION NUMBER, FILING DATE, NAME OF APPLICANT, and TITLE OF INVENTION when inquiring about this application. Fees transmitted by check or draft are subject to collection. Please verify the accuracy of the data presented on this receipt. If an error is noted on this Filing Receipt, please write to the Application Processing Division's Customer Correction Branch within 10 days of receipt. Please provide a copy of the Filing Receipt with the changes noted thereon.

Applicant(s)

LEONARD FORBES; CORVALLIS, OR; KIE Y. AHN, CHAPPAQUA, NY.

FOREIGN FILING LICENSE GRANTED 12/09/97
TITLE
SILICON CARBIDE GATE TRANSISTOR AND FABRICATION PROCESS TO THE SILICON CARBIDE GATE TRANSISTOR AND FABRICATION PROCESS TO THE SILICON CARBIDE GATE TRANSISTOR AND FABRICATION PROCESS TO THE SILICON CARBIDE GATE TRANSISTOR AND FABRICATION PROCESS TO THE SILICON CARBIDE GATE TRANSISTOR AND FABRICATION PROCESS TO THE SILICON CARBIDE GATE TRANSISTOR AND FABRICATION PROCESS TO THE SILICON CARBIDE GATE TRANSISTOR AND FABRICATION PROCESS TO THE SILICON CARBIDE GATE TRANSISTOR AND FABRICATION PROCESS TO THE SILICON CARBIDE GATE TRANSISTOR AND FABRICATION PROCESS TO THE SILICON CARBIDE GATE TRANSISTOR AND TRANSISTOR TRANSISTOR AND TRANSI

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Docket Nor: 303:326US1 which harshy acknowledged for the following in the United States Patent and In re Patent Application of: Leonard Forbes et a 866T O S NAL SILICON CARBIDE GATE TRANSTOR AND FABRICATION PROCESS Title: Docket No.: 303.326US1 Receipt is hereby acknowledged for the following in the United States Patent and Trademark Office: UTILITY PATENT APPLICATION: Specification ( 18 pgs., **CONTENTS:** including claims numbered 1 through, 22 and a 1 page Abstract); 4 Sheets of FORMAL DRAWINGS; a signed Combined Declaration and Power of Attorney (6 pgs); an Assignment of the invention to Micron Technology, Inc. (6 pgs.) and Recordation Form Cover Sheet (1 pg); a check in the amount of \$894.00 to cover the Filing Fee; a check in the amount of \$40.00 to cover the Assignment Recording Fee; and TRANSMITTAL SHEET. EXPRESS MAIL LABEL NO. EM031314287US Mailed: July 29, 1997 BAF/saj 8590 07/29/97 40.00 00303 326US1 40.00 POST OFFICE EXPRESS MAIL TO ADDRESSEE SNL97137459408 ORIGIN (POSTAL USE ONLY) IIPMENTS ONLY CUTED HASS BY I'VE BOX Flat Rate Envelope SEE REVERSE SIDE FOR THE SERVICE GUARANTEE AND LIMITS ON THE INSURANCE COVERAGE CUSTOMER USE ONLY METHOD OF PAYMENT: 230 310 X554 Express Mail Corporate Acct. No. Federal Agency Acct. No. or Postal Service Acct. No. JUL 2-9-199 NO DELIVERY WEEKEND HOLIDAY FROM: (PLEASE PRINT) TO: (PLEASE PRINT) SCHWEGMAN MOESSNER G PATENT APPLICATION PO DOX 2938 ASSISTANT COMMISSIUNER FOR PATENTS MN 55402-0438 WAS HINGTON DE 20231-0001 **94.00** 303.326USI-SAJ स्वस्थान्यस्यात् वस्य सम्बद्धाराज्यस्य द्वारः । ३०० Note: Susan J

In re Patent Application of: Leonard Forbe

Title:

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